N-Channel 60-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

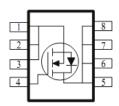
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- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY					
V _{DS} (V)	$V_{DS}(V)$ $r_{DS(on)}(m\Omega)$				
60	50 @ V _{GS} = 10V	6.4			
00	60 @ V _{GS} = 4.5V	5.9			







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter				Limit	Units	
Drain-Source Voltage		V_{DS}	60	V		
Gate-Source Voltage	V_{GS}	±20	V			
Continuous Dunis Communità		T _A =25°C	1	6.4		
Continuous Drain Current ^a		T _A =70°C	I _D	5.4	Α	
Pulsed Drain Current ^b	I_{DM}	30				
Continuous Source Current (Diode Conduction) a	I _S	4	А			
Danisa Disain ation a		T _A =25°C	P _D	3.1	W	
Power Dissipation ^a		T _A =70°C	' D	2.2	VV	
Operating Junction and Storage Temperature Range	T_J,T_sta	-55 to 150	°C			

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	40	°C/W		
Maximum Junction-to-Ambient	Steady State	' ' OJA	80	C/VV		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

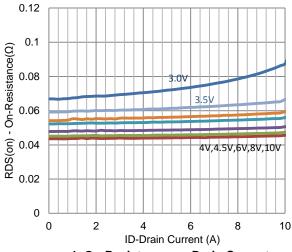
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1 uA			
Zero Gate Voltage Brain Gurrent	טטי	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25] uA		
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α		
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 5.1 \text{ A}$			50	0 mΩ		
Dialii-Source Off-Nesistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 5 \text{ A}$			60			
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 5.1 \text{ A}$		40		S		
Diode Forward Voltage	V_{SD}	$I_{S} = 2 \text{ A}, V_{GS} = 0 \text{ V}$		0.77		V		
	Dynamic							
Total Gate Charge	Q_g			3.8				
Gate-Source Charge	Q_gs	$V_{DS} = 30 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 5.1 \text{ A}$		1.6		nC		
Gate-Drain Charge	Q_gd			1.4				
Turn-On Delay Time	t _{d(on)}			3				
Rise Time	t _r	$V_{DD} = 30 \text{ V}, R_L = 5.9 \Omega, I_D = 5.1 \text{ A},$		4		ns		
Turn-Off Delay Time	t _{d(off)}	V_{GEN} = 10 V, R_{GEN} = 6 Ω		18		113		
Fall Time	t _f			5				
Input Capacitance	C_{iss}			382				
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		58		pF		
Reverse Transfer Capacitance	C _{rss}			32				

Notes

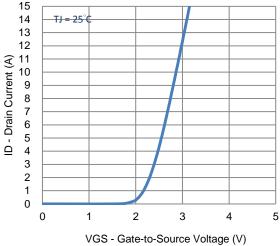
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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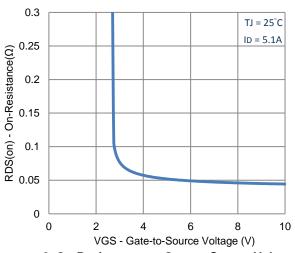
Typical Electrical Characteristics



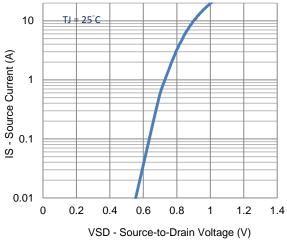
1. On-Resistance vs. Drain Current



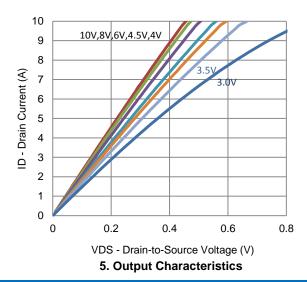
2. Transfer Characteristics

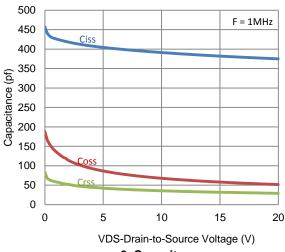


3. On-Resistance vs. Gate-to-Source Voltage



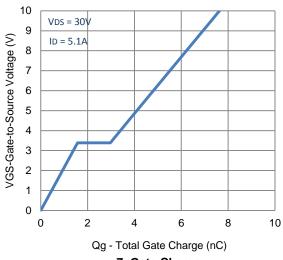
4. Drain-to-Source Forward Voltage

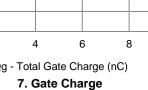




6. Capacitance

Typical Electrical Characteristics

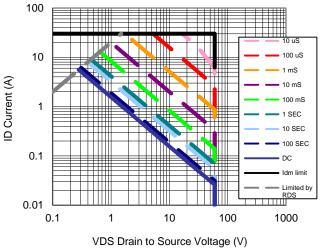




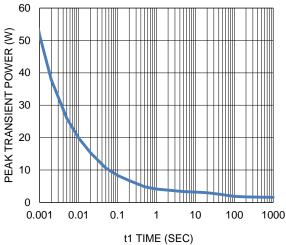
2.5 $RDS(on) - On-Resistance(\Omega) \\ (Normalized)$ 2 1.5 0.5 -25 25 75 100 -50 0 50 125 150

TJ -JunctionTemperature(°C)

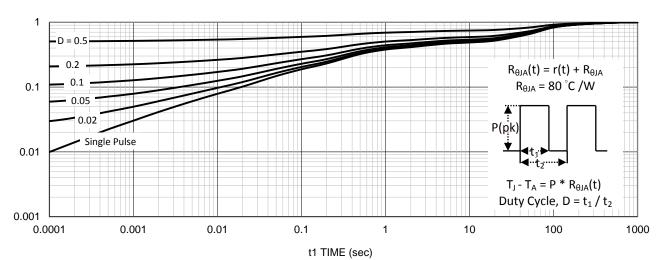




9. Safe Operating Area



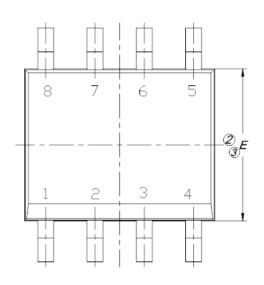
10. Single Pulse Maximum Power Dissipation

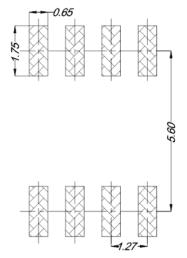


11. Normalized Thermal Transient Junction to Ambient

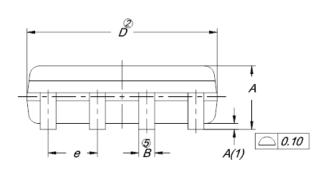
Package Information

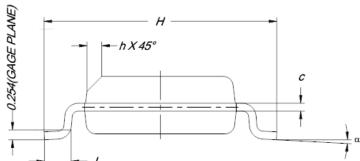
Land Pattern (Only for Reference)





DIM	MILLIMETERS						
DIM.	MIN.	NOM.	MAX.				
Α	1.35	1.55	1.75				
A(1)	0.10	0.18	0.25				
В	0.38	0.45	0.51				
С	0.19	0.22	0.25				
D	4.80	4.90	5.00				
E	3.80	3.90	4.00				
е	1.27 BSC						
Н	5.80	6.00	6.20				
L	0.50	0.72	0.93				
α	0°	4°	8°				
h	0.25	0.38	0.50				





Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension Br Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess
 Of Br Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The
 Foot.